

# **DMP2900UW-7 Datasheet**

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| DMP2900UW-7-DG   |
|--|
| Diodes Incorporated                                      |
| DMP2900UW-7  |
| MOSFET BVDSS: 8V-24V SOT323                              |
| P-Channel 20 V 600mA (Ta) 300mW Surface Mount<br>SOT-323 |
|  |

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# Purchase and inquiry

| Manufacturer Product Number:            | Manufacturer:                           |
|---|---|
| DMP2900UW-7                             | Diodes Incorporated                     |
| Series:                                 | Product Status:                         |
|   | Active                                  |
| FET Type:                               | Technology:                             |
| P-Channel                               | MOSFET (Metal Oxide)                    |
| Drain to Source Voltage (Vdss):         | Current - Continuous Drain (ld) @ 25°C: |
| 20 V                                    | 600mA (Ta)                              |
| Drive Voltage (Max Rds On, Min Rds On): | Rds On (Max) @ ld, Vgs:                 |
| 1.8V, 4.5V                              | 750mOhm @ 430mA, 4.5V                   |
| Vgs(th) (Max) @ ld:                     | Gate Charge (Qg) (Max) @ Vgs:           |
| 1V @ 250μΑ                              | 0.7 nC @ 4.5 V                          |
| Vgs (Max):                              | Input Capacitance (Ciss) (Max) @ Vds:   |
| ±6V                                     | 49 pF @ 16 V                            |
| FET Feature:                            | Power Dissipation (Max):                |
| -                                       | 300mW                                   |
| Operating Temperature:                  | Mounting Type:                          |
| -55°C ~ 150°C (TJ)                      | Surface Mount                           |
| Supplier Device Package:                | Package / Case:                         |
| SOT-323                                 | SC-70, SOT-323                          |
| Base Product Number:                    |   |
| DMP2900                                 |   |

# **Environmental & Export classification**

| RoHS Status:     | Moisture Sensitivity Level (MSL): |
|------------------|-----------------------------------|
| ROHS3 Compliant  | 1 (Unlimited)                     |
| REACH Status:    | ECCN:                             |
| REACH Unaffected | EAR99                             |
| HTSUS:           |                                   |
| 8541.21.0095     |                                   |





**DMP2900UW** 

#### **Product Summary**

| BV <sub>DSS</sub> | Rds(on)                          | ID<br>TA = +25°C |
|-------------------|----------------------------------|------------------|
|                   | 750mΩ @ V <sub>GS</sub> = -4.5V  | -0.6A            |
| -20V              | 1050mΩ @ V <sub>GS</sub> = -2.5V | -0.5A            |
|                   | 1500mΩ @ V <sub>GS</sub> = -1.8V | -0.45A           |

#### **Description and Applications**

This new generation MOSFET is designed to minimize the on-state resistance ( $R_{DS(ON)}$ ) yet maintain superior switching performance, which makes it ideal for high-efficiency power management applications.

- DC-DC Converters
- Load Switch
- Power Management Functions



#### **Features and Benefits**

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

#### **Mechanical Data**

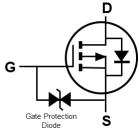
- Case: SOT323
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Terminals: Finish Matte Tin Annealed Over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208 3
- Weight: 0.006 grams (Approximate)



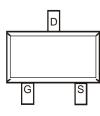


**SOT323** 

Top View



Equivalent Circuit



Top View

#### Ordering Information (Note 4)

| Part Number  | Case   | Packaging          |
|--------------|--------|--------------------|
| DMP2900UW-7  | SOT323 | 3,000/Tape & Reel  |
| DMP2900UW-13 | SOT323 | 10,000/Tape & Reel |

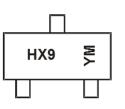
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**



HX9 = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: I = 2021) M = Month (ex: 9 = September)

Date Code Key

| Date Code Rey |      |     |      |      |      |      |      |      |      |      |      |      |
|---------------|------|-----|------|------|------|------|------|------|------|------|------|------|
| Year          | 2018 |     | 2021 | 2022 | 2023 | 2024 | 2025 | 2026 | 2027 | 2028 | 2029 | 2030 |
| Code          | F    |     | _    | J    | K    | L    | М    | Ν    | 0    | Р    | R    | s    |
|               | r    |     |      |      |      |      |      |      |      |      |      |      |
| Month         | Jan  | Feb | Mar  | Apr  | Мау  | Jun  | Jul  | Aug  | Sep  | Oct  | Nov  | Dec  |
|               |      |     |      |      |      |      |      |      |      |      |      |      |



#### Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic                                     | Symbol           | Value        | Unit |
|--|------------------|--------------|------|
| Drain-Source Voltage                               | Vdss             | -20          | V    |
| Gate-Source Voltage                                | V <sub>GSS</sub> | ±6           | V    |
| Continuous Drain Current (Note 6) $V_{GS}$ = -4.5V | lo               | -0.6<br>-0.5 | А    |
| Maximum Body Diode Forward Current (Note 6)        | ls               | -0.45        | A    |
| Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%  | Ідм              | -2.5         | A    |

#### **Thermal Characteristics**

| Characteristic                                   |              | Symbol   | Value       | Unit |
|--|--------------|----------|-------------|------|
| Total Power Dissipation (Note 5)                 |              | PD       | 0.3         | W    |
| Thermal Resistance, Junction to Ambient (Note 5) | Steady State | Reja     | 393         | °C/W |
| Total Power Dissipation (Note 6)                 |              | PD       | 0.5         | W    |
| Thermal Resistance, Junction to Ambient (Note 6) | Steady State | Rəja     | 272         | °C/W |
| Operating and Storage Temperature Range          |              | TJ, TSTG | -55 to +150 | °C   |

#### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic                             | Symbol                       | Min  | Тур    | Max  | Unit   | Test Condition   |  |  |  |
|--|------------------------------|------|--------|------|--|--|--|--|--|
| OFF CHARACTERISTICS (Note 7)               | OFF CHARACTERISTICS (Note 7) |      |        |      |  |  |  |  |  |
| Drain-Source Breakdown Voltage             | BV <sub>DSS</sub>            | -20  | —      | —    | V  | $V_{GS} = 0V, I_D = -250 \mu A$  |  |  |  |
| Zero Gate Voltage Drain Current TJ = +25°C | IDSS                         |      | _      | -100 | nA   | $V_{DS} = -20V, V_{GS} = 0V$   |  |  |  |
| Gate-Source Leakage                        | I <sub>GSS</sub>             |      | —      | ±2.0 | μA   | $V_{GS} = \pm 4.5 V$ , $V_{DS} = 0 V$                                  |  |  |  |
| ON CHARACTERISTICS (Note 7)                |                              |      |        |      |  |  |  |  |  |
| Gate Threshold Voltage                     | VGS(TH)                      | -0.5 | —      | -1.0 | V  | $V_{DS} = V_{GS}$ , $I_D = -250 \mu A$                                 |  |  |  |
|  |                              |      |        | 0.75 |  | $V_{GS} = -4.5V, I_{D} = -430mA$                                       |  |  |  |
| Static Drain-Source On-Resistance          | RDS(ON)                      | —    | — 1.05 | Ω    | V <sub>GS</sub> = -2.5V, I <sub>D</sub> = -300mA |  |  |  |  |
|  |                              |      |        | 1.5  |  | V <sub>GS</sub> = -1.8V, I <sub>D</sub> = -150mA                       |  |  |  |
| Diode Forward Voltage                      | V <sub>SD</sub>              | _    |        | -1.2 | V  | $V_{GS} = 0V, I_{S} = -150mA$  |  |  |  |
| DYNAMIC CHARACTERISTICS (Note 8)           |                              |      |        |      |  | -  |  |  |  |
| Input Capacitance                          | Ciss                         |      | 49     |      | pF   |  |  |  |  |
| Output Capacitance                         | Coss                         |      | 12     | —    | pF   | V <sub>DS</sub> = -16V, V <sub>GS</sub> = 0V,<br>f = 1.0MHz            |  |  |  |
| Reverse Transfer Capacitance               | Crss                         | —    | 3.4    | _    | pF   | 1 = 1.00012  |  |  |  |
| Total Gate Charge                          | Qg                           | _    | 0.7    | —    | nC   |  |  |  |  |
| Gate-Source Charge                         | Qgs                          | _    | 0.1    |      | nC   | Vgs = -4.5V, Vds = -10V,<br>- In = -250mA                              |  |  |  |
| Gate-Drain Charge                          | Q <sub>gd</sub>              |      | 0.1    |      | nC   | -1D = -250 mA  |  |  |  |
| Turn-On Delay Time                         | tD(ON)                       |      | 16     |      | ns   |  |  |  |  |
| Turn-On Rise Time                          | tR                           |      | 15     |      | ns   | $V_{DD} = -10V, V_{GS} = -4.5V,$                                       |  |  |  |
| Turn-Off Delay Time                        | tD(OFF)                      |      | 213    | —    | ns   | R <sub>L</sub> = 47Ω, R <sub>G</sub> = 10Ω,<br>I <sub>D</sub> = -200mA |  |  |  |
| Turn-Off Fall Time                         | tF                           | _    | 89     |      | ns   | -20011A  |  |  |  |
| Reverse Recovery Time                      | t <sub>RR</sub>              | _    | 10.5   |      | ns   | I <sub>F</sub> = -1.0A, di/dt = 100A/µs                                |  |  |  |
| Reverse Recovery Charge                    | $Q_{RR}$                     | -    | 1.8    | —    | nC   | $r_{\rm F} = -1.0$ A, u/ul – 100 A/µs                                  |  |  |  |

 Device mounted on FR-4 substrate PCB, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PCB, 2oz copper, with 1inch square copper plate.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to production testing. Notes:



#### **DMP2900UW**

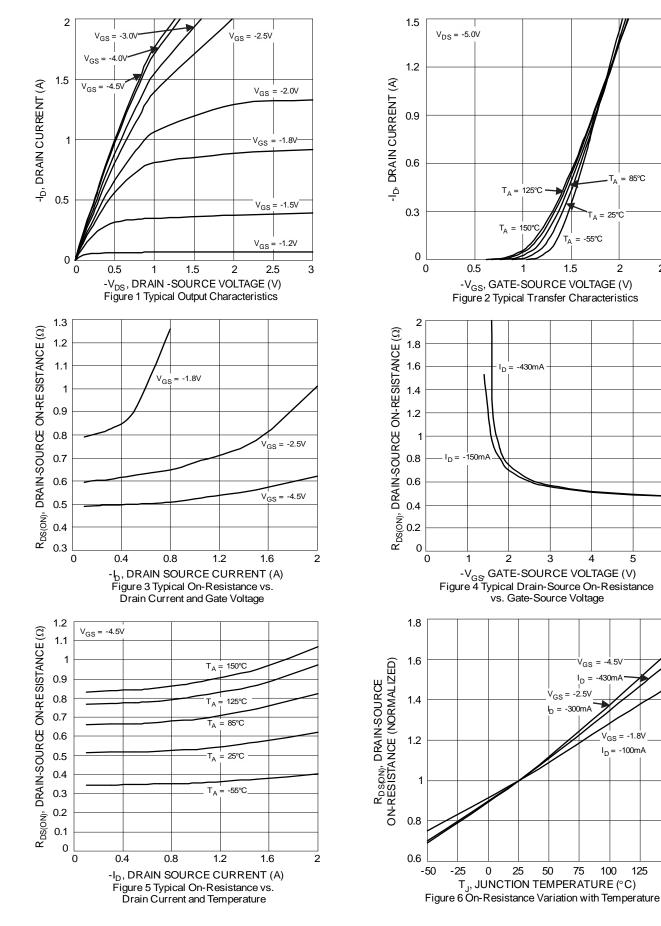
= 85°C

2

5

6

2.5

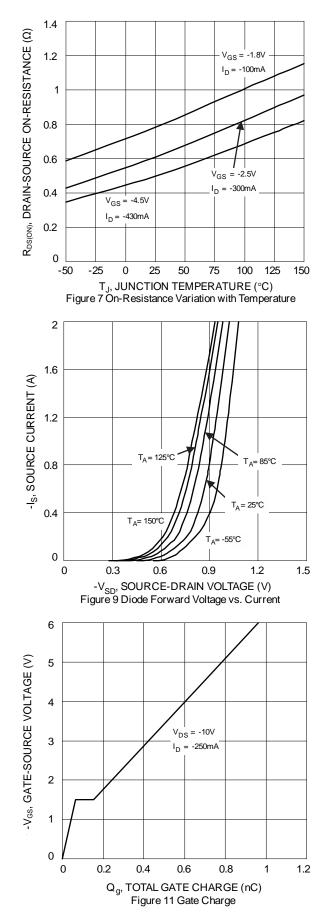


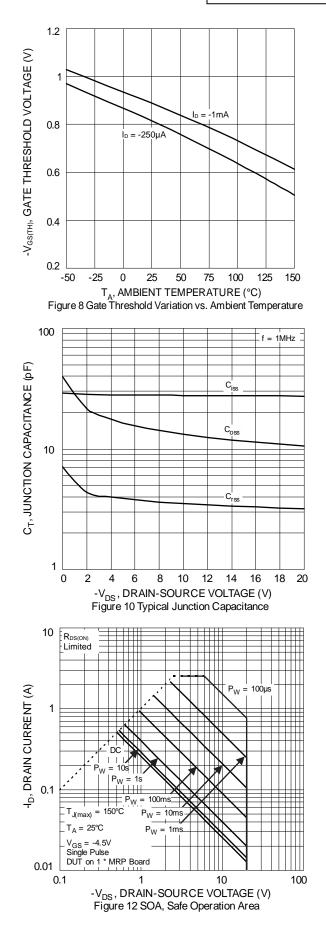
150

125



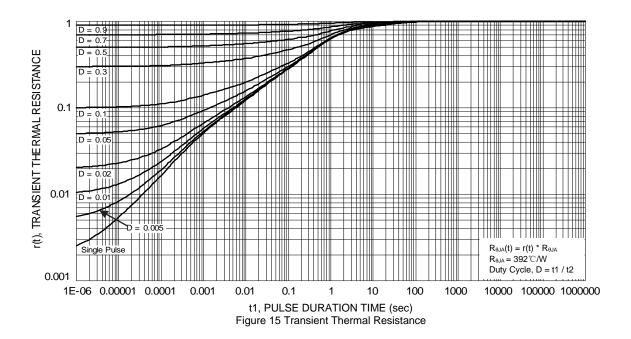
## **DMP2900UW**





DMP2900UW Document number: DS41296 Rev. 5 - 2

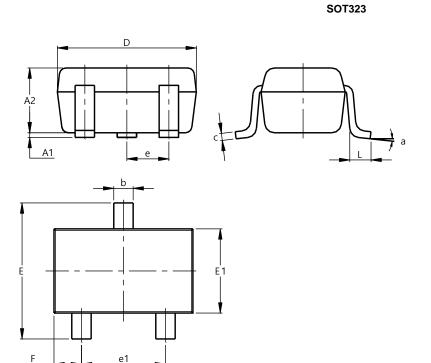






#### **Package Outline Dimensions**

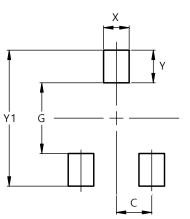
Please see http://www.diodes.com/package-outlines.html for the latest version.



|     | SC    | T323    |       |
|-----|-------|---------|-------|
| Dim | Min   | Max     | Тур   |
| A1  | 0.00  | 0.10    | 0.05  |
| A2  | 0.90  | 1.00    | 0.95  |
| b   | 0.25  | 0.40    | 0.30  |
| С   | 0.10  | 0.18    | 0.11  |
| D   | 1.80  | 2.20    | 2.15  |
| Е   | 2.00  | 2.20    | 2.10  |
| E1  | 1.15  | 1.35    | 1.30  |
| е   | C     | ).650 B | SC    |
| e1  | 1.20  | 1.40    | 1.30  |
| F   | 0.375 | 0.475   | 0.425 |
| L   | 0.25  | 0.40    | 0.30  |
| а   | 0°    | 8°      |       |
| All | Dimen | sions   | in mm |

#### **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



| SOT323 |
|--------|
|--------|

| Dimensions | Value<br>(in mm) |
|------------|------------------|
| С          | 0.650            |
| G          | 1.300            |
| Х          | 0.470            |
| Y          | 0.600            |
| Y1         | 2.500            |



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